

Plastic Deformation and Metalworking of Inorganic Thermoelectric Materials

Tian-Ran Wei

School of Materials Science and Engineering, Shanghai Jiao Tong University, P. R. China

Email: tianran_wei@sjtu.edu.cn

The discovery of exceptional plasticity in a few semiconductors has challenged our conventional understanding of their mechanical properties, promising a shift in their processing and application paradigms. In this talk, I will report our recent progress on the understanding of the metal-like plasticity from different perspectives. (i) As to microstructures, we found an inherent quasi-bcc anionic sublattice hiding in the monoclinic structure of Ag₂S-based material, which gives rise to multiple slip systems that are identified by TEM analysis. We also deciphered the cross-layer slip and a martensitic transformation in InSe crystals, which are key to the plastic deformation. (ii) Guided by the energy principle of “easy to slip, hard to cleave”, we proposed a “deformability factor” and developed a high-throughput procedure, which screened out a series of ductile semiconductors, including high-performance thermoelectric materials. (iii) We enriched the deformability factor and well modeled the temperature-dependent plasticity. This model accurately captured the brittle-to-ductile transition temperature and picked several semiconductors that turn ductile below 500 K. We thus enabled metalworking in these materials, yielding high-quality, free-standing foils and high-performance thermoelectric devices.

References:

- [1] T.-R. Wei et al., Science 369 542-545 (2020).
- [2] Z. Gao et al., Nature Materials 24 1538–1544 (2025).
- [3] Z. Gao et al., Nature Communications 13 7491 (2022).
- [4] Y. Sun et al., Science Advances 10 eado9593 (2024).
- [5] H. Chen et al., Advanced Energy Materials 14 2303473 (2024).